

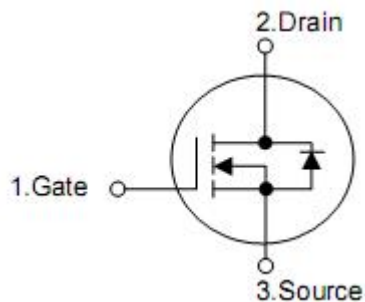
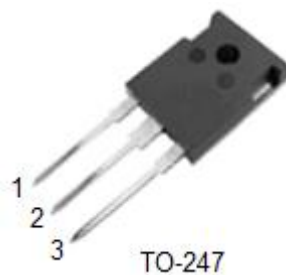
1. Features

- n RoHS Compliant
- n $R_{DS(ON),typ.}=2.4\Omega@V_{GS}=10V$
- n Low Gate Charge Minimize Switching Loss
- n Fast Recovery Body Diode

2. Applications

- n High Voltage Power Supplies
- n Capacitor Discharge
- n Pulse Circuits

3. Pin configuration



Pin	Function
1	Gate
2	Drain
3	Source

4. Ordering Information

Part Number	Package	Brand
KNM62150A	TO-247	KIA

5. Absolute maximum ratings

(T_C= 25°C , unless otherwise specified)

Parameter	Symbol	Rating	Unit	
Drain-to-Source Voltage	V _{DSS}	1500	V	
Gate-to-Source Voltage	V _{GSS}	±30		
Continuous Drain Current	I _D	11	A	
Pulsed Drain Current at V _{GS} =10V	I _{DM}	44		
Single Pulse Avalanche Energy	E _{AS}	350	mJ	
Maximum Power Dissipation	P _D	T _C =25°C	312	W
		Derate above 25°C	2.5	W/°C
Soldering Temperature Distance of 1.6mm from case for 10 seconds	T _L	300	°C	
Storage Temperature Range	T _J &T _{STG}	-55 to 150		

Caution: Stresses greater than those listed in the “Absolute Maximum Ratings” may cause permanent damage to the device.

6. Thermal characteristics

Parameter	Symbol	Rating	Unit
Thermal Resistance, Junction-to-Case	R _{θJC}	0.4	°C/W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	50	°C/W

7. Electrical characteristics

(T_J=25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	1500	-	-	V
Drain-source leakage current	I _{DSS}	V _{DS} =1500V, V _{GS} =0V	-	-	1	uA
		V _{DS} =1200V, T _C =125°C			500	uA
Gate-source forward leakage	I _{GSS}	V _{GS} =±30V, V _{DS} =0V	-	-	±100	nA
Drain-source on-resistance	R _{DS(on)}	V _{GS} =10V, I _D =5.5A	-	2.4	3.2	Ω
Gate threshold voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250uA	2.5	-	4.5	V
Gate Resistance	R _g	f=1 MHz Gate DC Bias=0, Test signal level=20mV open drain	-	1.19	-	Ω
Input capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V f=1MHz	-	3876	-	pF
Reverse transfer capacitance	C _{rss}		-	170	-	pF
Output capacitance	C _{oss}		-	195	-	pF
Total gate charge(10V)	Q _g	V _{DD} =750V, I _D =11A V _{GS} =0~10V	-	83.2	-	nC
Gate-source charge	Q _{gs}		-	21.6	-	nC
Gate-drain charge	Q _{gd}		-	25.4	-	nC
Turn-on delay time	t _{d(on)}	V _{DD} =750V, V _{GS} =10V, R _G =25Ω, I _D =11A		62		ns
Rise time	t _r			188		ns
Turn-off delay time	t _{d(off)}			120		ns
Fall time	t _f			158		ns
Continuous Source Current ²⁾	I _{SD}	Integral PN-diode in MOSFET			11	A
Pulsed Source Current ²⁾	I _{SM}		-	-	44	A
Diode forward voltage	V _{SD}	I _S =11A, V _{GS} =0V,	-	-	1.5	V
Reverse Recovery Time	t _{rr}	V _{GS} =0V, I _F =11A, dI _F /dt=100A/μs	-	449	-	nS
Reverse Recovery Charge	Q _{rr}		-	3.58	-	nC

Note:

1) T_J=+25°C to +150°C

2) Pulse width ≤ 380us; duty cycle ≤ 2%.

8. Test circuits and waveforms

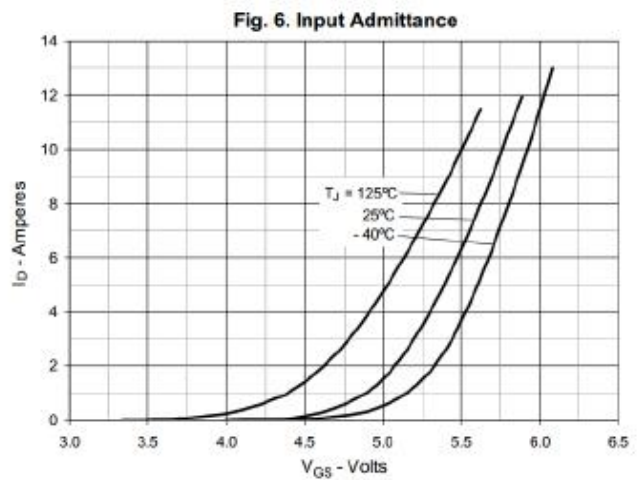
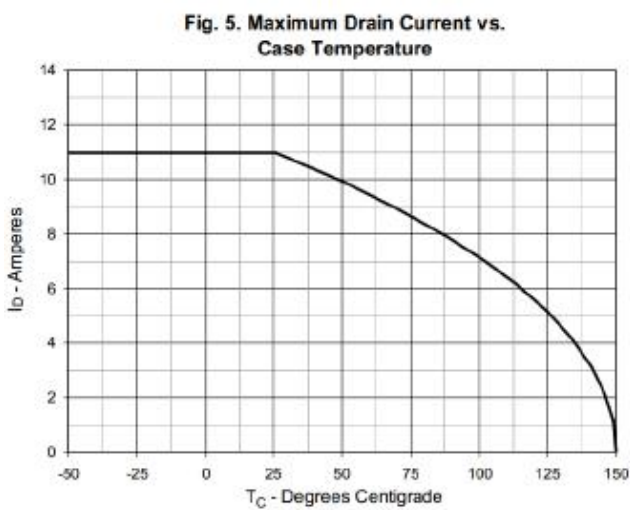
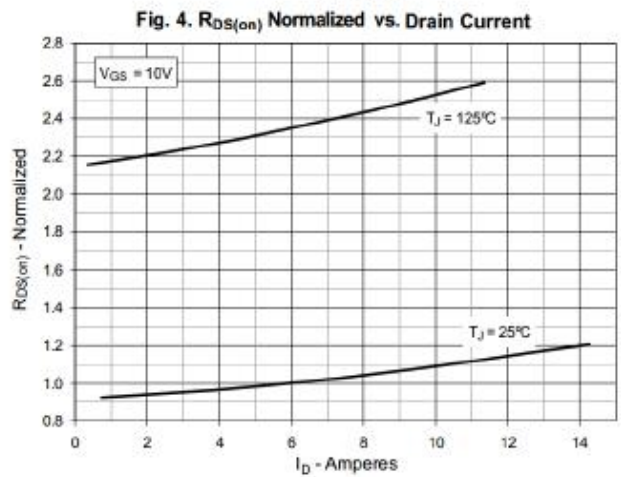
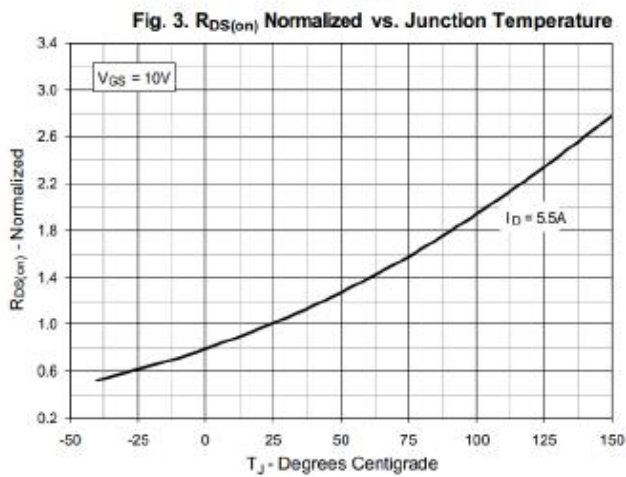
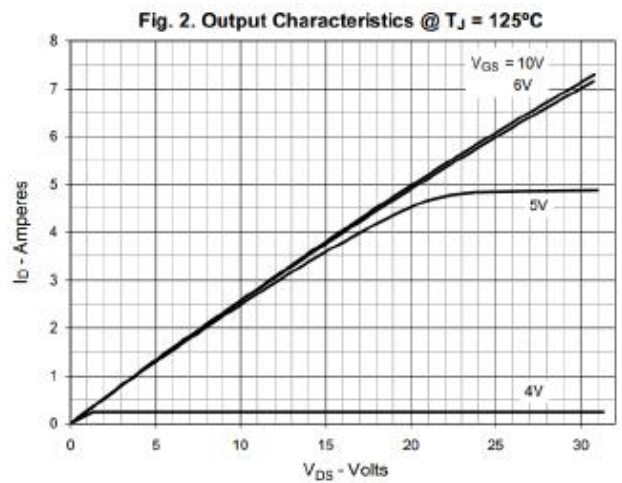
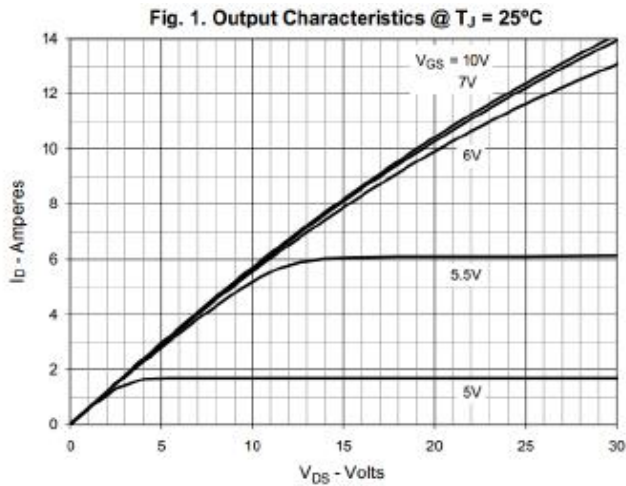


Fig. 7. Capacitance

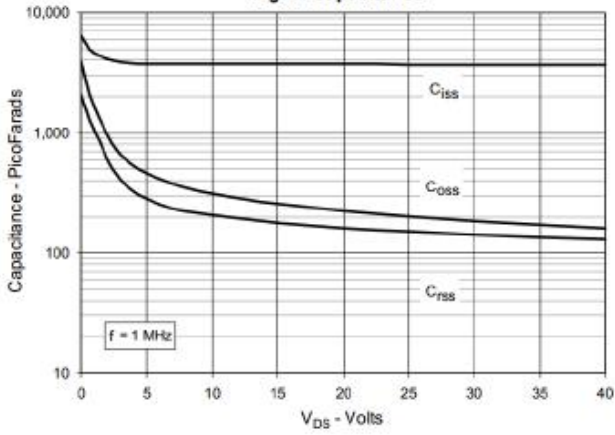


Fig. 8. Forward Voltage Drop of Intrinsic Diode

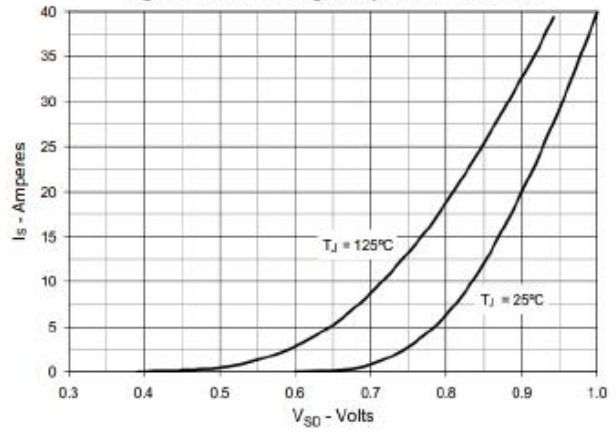


Fig. 9. Gate Charge

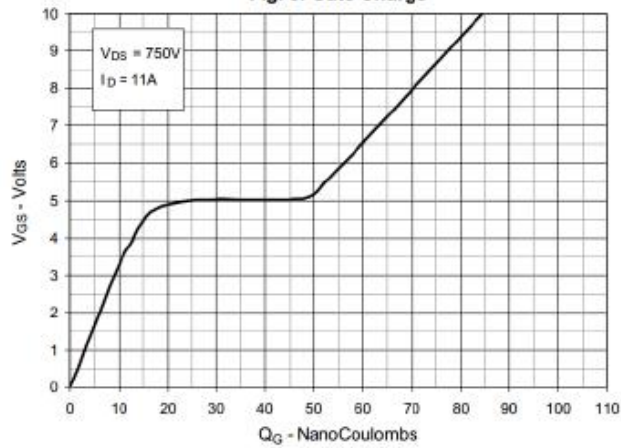
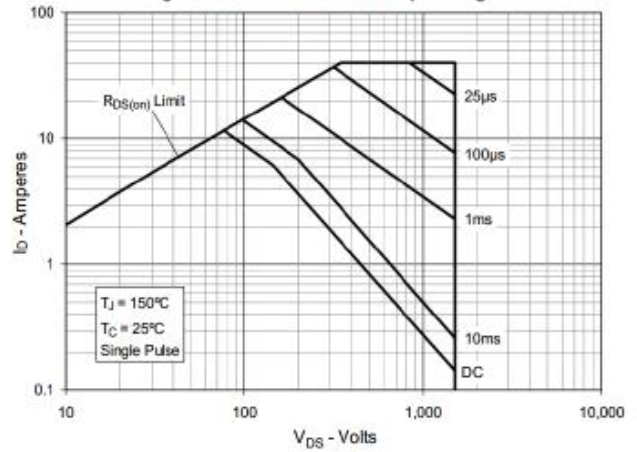


Fig. 10. Forward-Bias Safe Operating Area



9. Test Circuits and Waveform

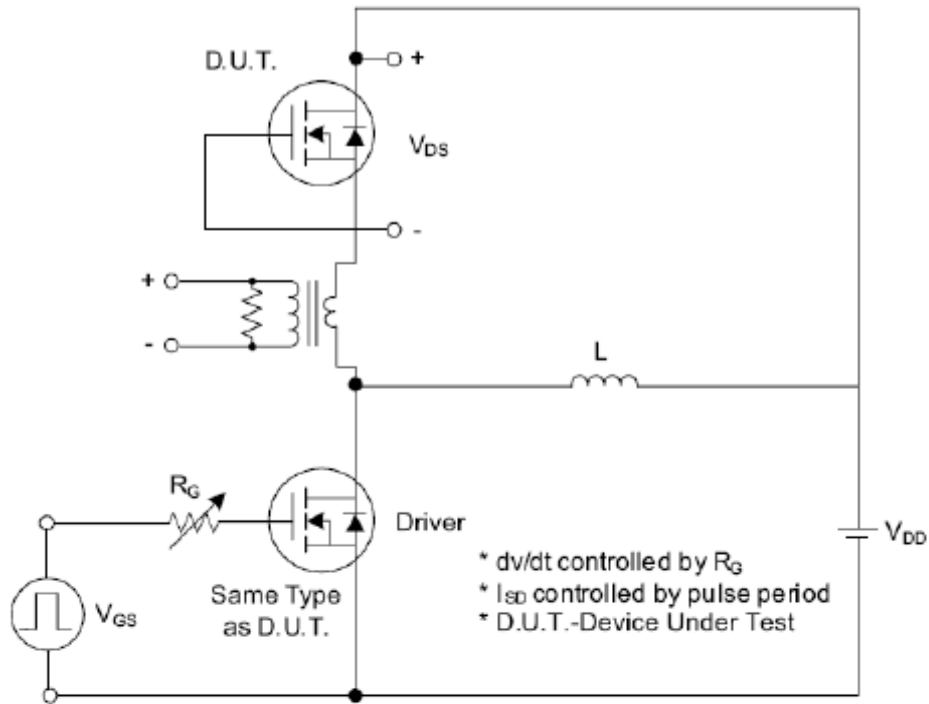


Fig. 1.1 Peak Diode Recovery dv/dt Test Circuit

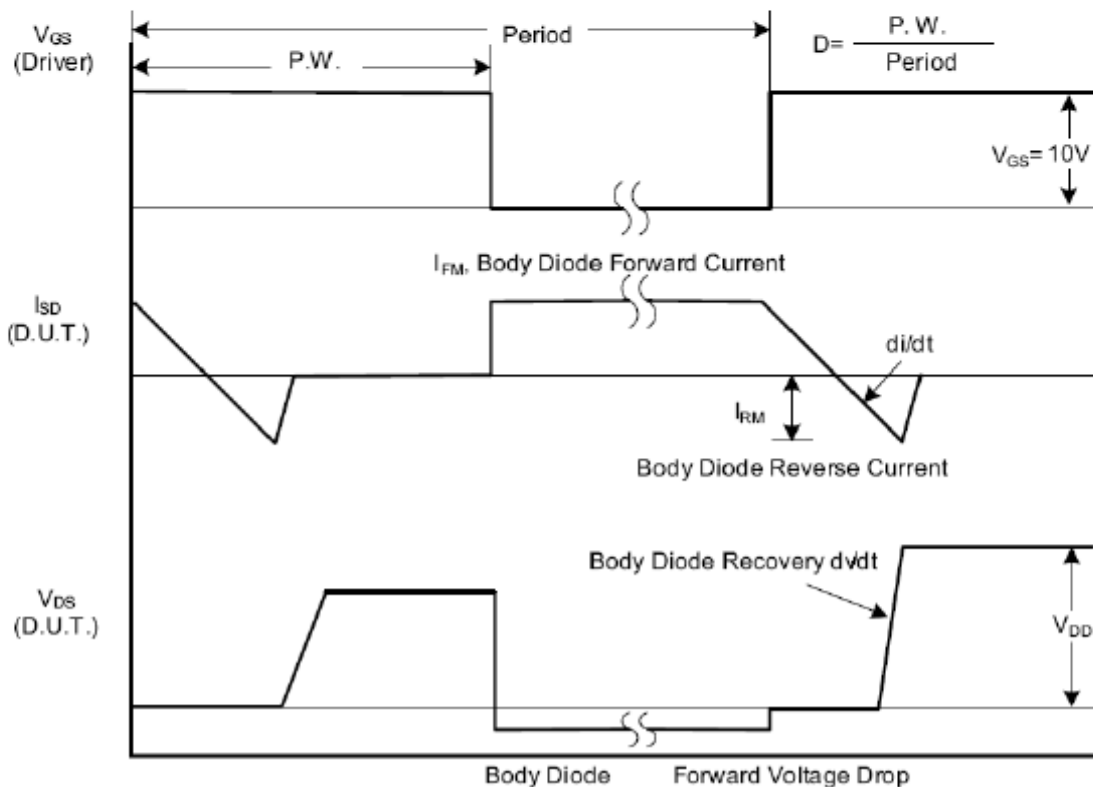


Fig. 1.2 Peak Diode Recovery dv/dt Waveforms

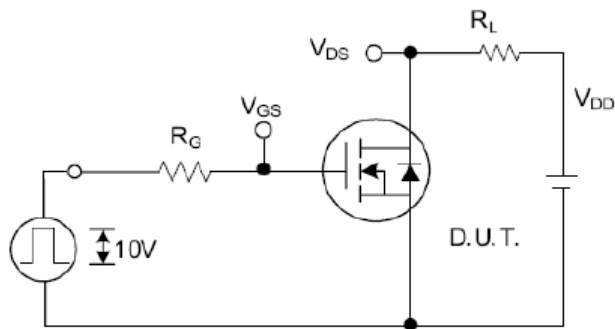


Fig. 2.1 Switching Test Circuit

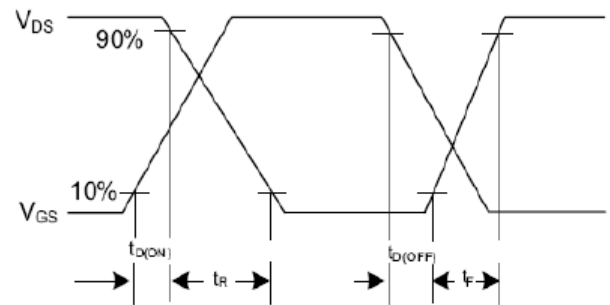


Fig. 2.2 Switching Waveforms

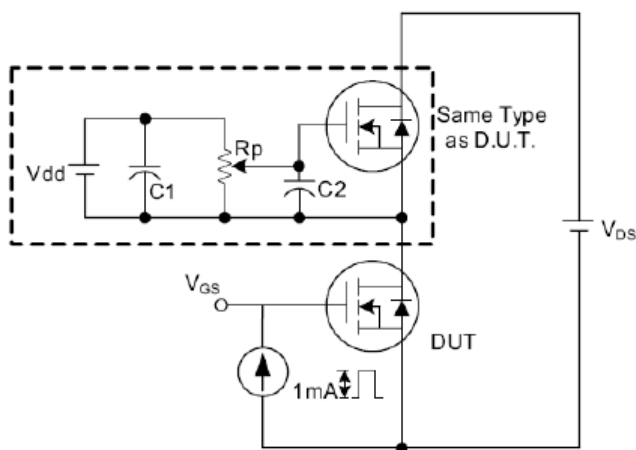


Fig. 3. 1 Gate Charge Test Circuit

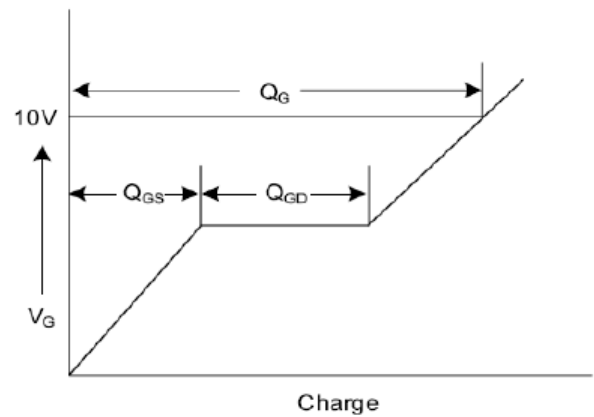


Fig. 3 . 2 Gate Charge Waveform

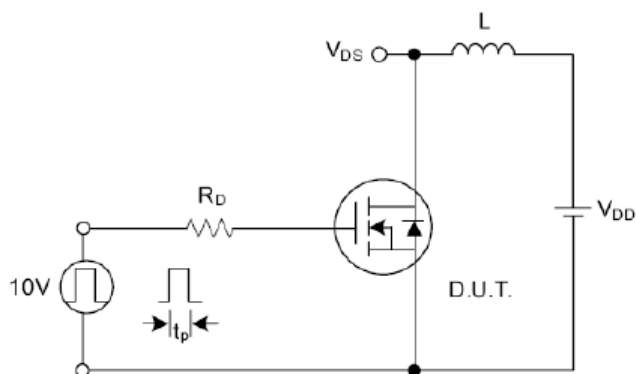


Fig. 4.1 Unclamped Inductive Switching Test Circuit

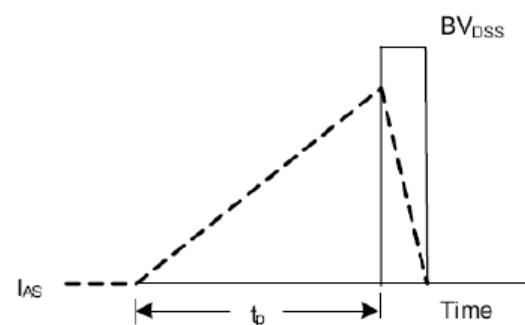


Fig. 4.2 Unclamped Inductive Switching Waveforms

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [MOSFET](#) category:

Click to view products by [KIA](#) manufacturer:

Other Similar products are found below :

[IRFD120](#) [JANTX2N5237](#) [BUK455-60A/B](#) [MIC4420CM-TR](#) [VN1206L](#) [NDP4060](#) [SI4482DY](#) [IPS70R2K0CEAKMA1](#) [SQD23N06-31L-GE3](#)
[TK16J60W,S1VQ\(O](#) [2SK2614\(TE16L1,Q\)](#) [DMN1017UCP3-7](#) [DMN1053UCP4-7](#) [SQJ469EP-T1-GE3](#) [NTE2384](#) [DMC2700UDMQ-7](#)
[DMN2080UCB4-7](#) [DMN61D9UWQ-13](#) [US6M2GTR](#) [DMN31D5UDJ-7](#) [DMP22D4UFO-7B](#) [DMN1006UCA6-7](#) [DMN16M9UCA6-7](#)
[STF5N65M6](#) [IRF40H233XTMA1](#) [STU5N65M6](#) [DMN6022SSD-13](#) [DMN13M9UCA6-7](#) [DMTH10H4M6SPS-13](#) [DMN2990UFB-7B](#)
[IPB80P04P405ATMA2](#) [2N7002W-G](#) [MCAC30N06Y-TP](#) [MCQ7328-TP](#) [BXP7N65D](#) [BXP4N65F](#) [AOL1454G](#) [WMJ80N60C4](#) [BXP2N20L](#)
[BXP2N65D](#) [BXT1150N10J](#) [BXT1700P06M](#) [TSM60NB380CP](#) [ROG](#) [RQ7L055BGTCR](#) [DMNH15H110SK3-13](#) [SLF10N65ABV2](#)
[BSO203SP](#) [BSO211P](#) [IPA60R230P6](#) [IPA60R460CE](#)